

- Low Input Offset Voltage . . . 0.5 mV Max
- Low Power Consumption
- Wide Common-Mode and Differential Voltage Ranges
- Low Input Bias and Offset Currents
- High Input Impedance . . . JFET-Input Stage
- Internal Frequency Compensation
- Latch-Up-Free Operation
- High Slew Rate . . . 18 V/μs Typ
- Low Total Harmonic Distortion 0.003% Typ

description

These JFET-input operational amplifiers incorporate well-matched high-voltage JFET and bipolar transistors in a monolithic integrated circuit. They feature low input offset voltage, high slew rate, low input bias and offset currents, and low temperature coefficient of input offset voltage. Offset-voltage adjustment is provided for the TL087 and TL088.

The C-suffix devices are characterized for operation from 0°C to 70°C, and the I-suffix devices are characterized for operation from –40°C to 85°C. The M-suffix devices are characterized for operation over the full military temperature range of –55°C to 125°C.

AVAILABLE OPTIONS

| T _A | TYPE | V _{IO} max AT 25°C | PACKAGE | | | |
|----------------------|--------|--------------------------------|----------------------|----------------------|--------------------|-------------|
| | | | SMALL OUTLINE (D) | CERAMIC DIP (JG) | PLASTIC DIP (P) | FLAT (U) |
| 0°C to 70°C | Single | 0.5 mV 1 mV | TL087CD TL088CD | TL087CJG TL088CJG | TL087CP TL088CP | |
| | Dual | 0.5 mV 1 mV | TL287CD TL288CD | TL287CJG TL288CJG | TL287CP TL288CP | |
| –40°C to 85°C | Single | 0.5 mV 1 mV | TL087ID TL088ID | TL087IJG TL088IJG | TL087IP TL088IP | |
| | Dual | 0.5 mV 1 mV | TL287ID TL288ID | TL287IJG TL288IJG | TL287IP TL288IP | |
| –55°C to 125°C | Single | 1 mV | | TL088MJG | | TL088MU |
| | Dual | 1 mV | | TL288MJG | | TL288MU |

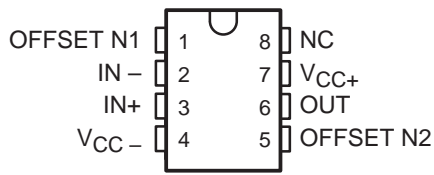
The D package is available taped and reeled. Add the suffix R to the device type (e.g., TL087CDR).



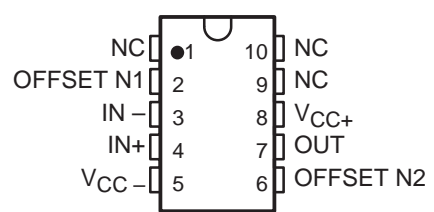
TL087, TL088, TL287, TL288 JFET-INPUT OPERATIONAL AMPLIFIERS

SLOS082A – D2484, MARCH 1979 – REVISED JANUARY 1993

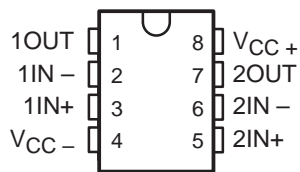
TL087, TL088
D, JG, OR P PACKAGE
(TOP VIEW)



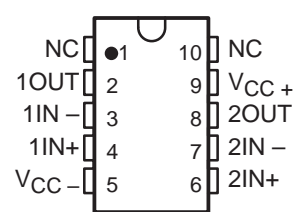
TL088M
U PACKAGE
(TOP VIEW)



TL287, TL288
D, JG, OR P PACKAGE
(TOP VIEW)

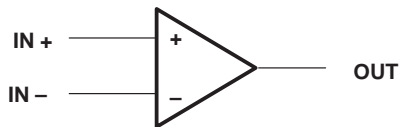


TL288M
U PACKAGE
(TOP VIEW)



NC – No internal connection

symbol (each amplifier)



TL087, TL088, TL287, TL288 JFET-INPUT OPERATIONAL AMPLIFIERS

SLOS082A – D2484, MARCH 1979 – REVISED JANUARY 1993

absolute maximum ratings over operating free-air temperature range (unless otherwise noted)

| | TL088M TL288M | TL087I TL088I TL287I TL288I | TL087C TL088C TL287C TL288C | UNIT | |
|--|------------------------------|--------------------------------------|--------------------------------------|--------------------|--------------------|
| Supply voltage, V_{CC+} (see Note 1) | 18 | 18 | 18 | V | |
| Supply voltage, V_{CC-} (see Note 1) | -18 | -18 | -18 | V | |
| Differential input voltage (see Note 2) | ± 30 | ± 30 | ± 30 | V | |
| Input voltage (see Notes 1 and 3) | ± 15 | ± 15 | ± 15 | V | |
| Input current, I_I (each Input) | ± 1 | ± 1 | ± 1 | mA | |
| Output current, I_O (each output) | ± 80 | ± 80 | ± 80 | mA | |
| Total V_{CC+} terminal current | 160 | 160 | 160 | mA | |
| Total V_{CC-} terminal current | -160 | -160 | -160 | mA | |
| Duration of output short circuit (see Note 4) | unlimited | unlimited | unlimited | | |
| Continuous total dissipation | See Dissipation Rating Table | | | | |
| Operating free-air temperature range | -55 to 125 | -25 to 85 | 0 to 70 | $^{\circ}\text{C}$ | |
| Storage temperature range | -65 to 150 | -65 to 150 | -65 to 150 | $^{\circ}\text{C}$ | |
| Lead temperature 1,6 mm (1/16 inch) from case for 60 seconds | JG or U package | 300 | 300 | 300 | $^{\circ}\text{C}$ |
| Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds | D or P package | | 260 | 260 | $^{\circ}\text{C}$ |

- NOTES: 1. All voltage values, except differential voltages, are with respect to the midpoint between V_{CC+} and V_{CC-} .
 2. Differential voltages are at the noninverting input terminal with respect to the inverting input terminal.
 3. The magnitude of the input voltage must never exceed the magnitude of the supply voltage or 15 V, whichever is less.
 4. The output may be shorted to ground or to either supply. Temperature and/or supply voltages must be limited to ensure that the dissipation rating is not exceeded.

DISSIPATION RATING TABLE

| PACKAGE | $T_A \leq 25^{\circ}\text{C}$ | DERATING FACTOR ABOVE $T_A = 25^{\circ}\text{C}$ | $T_A = 70^{\circ}\text{C}$ | $T_A = 85^{\circ}\text{C}$ | $T_A = 125^{\circ}\text{C}$ |
|---------|-------------------------------|---|----------------------------|----------------------------|-----------------------------|
| | POWER RATING | | POWER RATING | POWER RATING | POWER RATING |
| D | 725 mW | 5.8 mW/ $^{\circ}\text{C}$ | 464 mW | 377 mW | N/A |
| JG | 1050 mW | 8.4 mW/ $^{\circ}\text{C}$ | 672 mW | 546 mW | 210 mW |
| P | 1000 mW | 8.0 mW/ $^{\circ}\text{C}$ | 640 mW | 520 mW | N/A |
| U | 675 mW | 5.4 mW/ $^{\circ}\text{C}$ | 432 mW | 351 mW | 135 mW |

recommended operating conditions

| | | C-SUFFIX | | | I-SUFFIX | | | M-SUFFIX | | | UNIT |
|---------------------------------------|-------------------------------|----------|-----|---------|----------|-----|---------|----------|-----|----------|--------------------|
| | | MIN | NOM | MAX | MIN | NOM | MAX | MIN | NOM | MAX | |
| Supply voltage, V_{CC} | | ± 5 | | ± 5 | ± 5 | | ± 5 | ± 5 | | ± 15 | V |
| Common-mode input voltage, V_{IC} | $V_{CC\pm} = \pm 5\text{ V}$ | -1 | | 4 | -1 | | 4 | -1 | | 4 | V |
| | $V_{CC\pm} = \pm 15\text{ V}$ | -11 | | 11 | -11 | | 11 | -11 | | 11 | V |
| Input voltage, V_I | $V_{CC\pm} = \pm 5\text{ V}$ | -1 | | 4 | -1 | | 4 | -1 | | 4 | V |
| | $V_{CC\pm} = \pm 15\text{ V}$ | -11 | | 11 | -11 | | 11 | -11 | | 11 | V |
| Operating free-air temperature, T_A | | 0 | | 70 | -40 | | 85 | -55 | | 125 | $^{\circ}\text{C}$ |

TL087, TL088, TL287, TL288 JFET-INPUT OPERATIONAL AMPLIFIERS

SLOS082A – D2484, MARCH 1979 – REVISED JANUARY 1993

electrical characteristics, $V_{CC\pm} = \pm 15\text{ V}$

| PARAMETER | TEST CONDITIONS† | | TL088M | | TL087I | | TL087C | | TL088C | | TL287C | | TL288C | | UNIT |
|--|---|--------------|--------------------------------------|-----|--------------------------------------|-----|--------------------------------------|-----|--------------------------------------|-----|--------------------------------------|-----|--------------------------------------|------------------------------|----------|
| | | | MIN | TYP | MAX | MIN | TYP | MAX | MIN | TYP | MAX | MIN | TYP | MAX | |
| V_{IO} Input offset voltage | $R_S = 50\ \Omega$, $V_O = 0$ $T_A = 25^\circ\text{C}$ | TL087, TL287 | | | | | | | | | | | | | |
| | $R_S = 50\ \Omega$, $V_O = 0$, $T_A = \text{full range}$ | TL088, TL288 | 0.1 | 3 | 0.1 | 1 | 0.1 | 1 | 0.1 | 1 | 0.1 | 1 | 1.5 | 2.5 | mV |
| | | TL087, TL287 | | | | | | | | | | | | | |
| | | TL088, TL288 | | | | | | | | | | | | | |
| α_{VIO} Temperature coefficient of input offset voltage | $R_S = 50\ \Omega$, $T_A = 25^\circ\text{C}$ to MAX | | 10 | | 8 | | 8 | | 8 | | 8 | | 8 | $\mu\text{V}/^\circ\text{C}$ | |
| I_{IO} Input offset current | $T_A = 25^\circ\text{C}$ | | 5 | | 5 | | 5 | | 5 | | 5 | | 5 | pA | |
| | $T_A = \text{full range}$ | | | 25 | | 3 | | 3 | | 3 | | 2 | | nA | |
| | $T_A = 25^\circ\text{C}$ | | 30 | | 30 | | 30 | | 30 | | 30 | | 30 | pA | |
| | $T_A = \text{full range}$ | | | 100 | | 20 | | 20 | | 20 | | 7 | | nA | |
| V_{ICR} Common-mode input voltage range | $T_A = 25^\circ\text{C}$ | | $V_{CC-} + 4$ to $V_{CC+} - 4$ | | $V_{CC-} + 4$ to $V_{CC+} - 4$ | | $V_{CC-} + 4$ to $V_{CC+} - 4$ | | $V_{CC-} + 4$ to $V_{CC+} - 4$ | | $V_{CC-} + 4$ to $V_{CC+} - 4$ | | $V_{CC-} + 4$ to $V_{CC+} - 4$ | | V |
| | $T_A = 25^\circ\text{C}$, $R_L = 10\ \text{k}\Omega$ | | 24 | 27 | 24 | 27 | 24 | 27 | 24 | 27 | 24 | 27 | 24 | 27 | |
| | $T_A = \text{full range}$, $R_L \geq 10\ \text{k}\Omega$ | | 24 | | 24 | | 24 | | 24 | | 24 | | 24 | | |
| | $T_A = \text{full range}$, $R_L \geq 2\ \text{k}\Omega$ | | 20 | | 20 | | 20 | | 20 | | 20 | | 20 | | |
| AVD Large-signal differential voltage amplification | $R_L \geq 2\ \text{k}\Omega$, $T_A = 25^\circ\text{C}$ | | 50 | 105 | 50 | 105 | 50 | 105 | 50 | 105 | 50 | 105 | 50 | 105 | V/mV |
| | $R_L \geq 2\ \text{k}\Omega$, $T_A = \text{full range}$ | | 25 | | 25 | | 25 | | 25 | | 25 | | 25 | | |
| | $T_A = 25^\circ\text{C}$ | | 3 | | 3 | | 3 | | 3 | | 3 | | 3 | MHz | |
| | $T_A = 25^\circ\text{C}$ | | 10^{12} | | 10^{12} | | 10^{12} | | 10^{12} | | 10^{12} | | 10^{12} | | Ω |
| CMRR Common-mode rejection ratio | $R_S = 50\ \Omega$, $V_{IC} = V_{ICR}$ min, $T_A = 25^\circ\text{C}$ | | 80 | 93 | 80 | 93 | 80 | 93 | 80 | 93 | 80 | 93 | 80 | 93 | dB |
| | $R_S = 50\ \Omega$, $V_{CC\pm} = \pm 9\ \text{V}$ to $\pm 15\ \text{V}$, $T_A = 25^\circ\text{C}$ | | 80 | 99 | 80 | 99 | 80 | 99 | 80 | 99 | 80 | 99 | 80 | 99 | dB |
| I_{CC} Supply current (per amplifier) | No load, $T_A = 25^\circ\text{C}$ | | 26 | 2.8 | 26 | 2.8 | 26 | 2.8 | 26 | 2.8 | 26 | 2.8 | 26 | 2.8 | mA |
| | $V_O = 0\ \text{V}$, $T_A = 25^\circ\text{C}$ | | | | | | | | | | | | | | |

† All characteristics are measured under open-loop conditions with zero common-mode input voltage unless otherwise specified. Full range for T_A is -55°C to 125°C for TL_88M; -40°C to 85°C for TL_8_I; and 0°C to 70°C for TL_8_C.

‡ Input bias currents of a FET-input operational amplifier are normal junction reverse currents, which are temperature sensitive. Pulse techniques must be used that will maintain the junction temperature as close to the ambient temperature as possible.

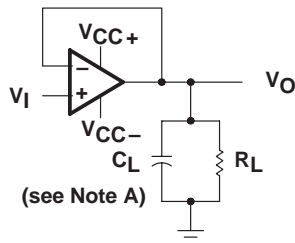
TL087, TL088, TL287, TL288 JFET-INPUT OPERATIONAL AMPLIFIERS

SLOS082A – D2484, MARCH 1979 – REVISED JANUARY 1993

operating characteristics $V_{CC} = \pm 15\text{ V}$, $T_A = 25^\circ\text{C}$

| PARAMETER | TEST CONDITIONS | TL088M, TL288M | | | TL087I, TL087C TL088I, TL088C | | | UNIT |
|--------------------------------------|--|----------------|-----|-----|----------------------------------|-----|-----|------------------------------|
| | | MIN | TYP | MAX | MIN | TYP | MAX | |
| SR Slew rate at unity gain | $V_I = 10\text{ V}$, $C_L = 100\text{ pF}$, $R_L = 2\text{ k}\Omega$, $A_{VD} = 1$ | | 18 | | 8 | 18 | | $\text{V}/\mu\text{s}$ |
| t_r Rise time | $V_I = 20\text{ mV}$, $R_L = 2\text{ k}\Omega$ | | 55 | | 55 | | | ns |
| Overshoot factor | $C_L = 100\text{ pF}$, $A_{VD} = 1$ | | 25% | | 25% | | | |
| V_n Equivalent input noise voltage | $R_S = 100\ \Omega$, $f = 1\text{ kHz}$ | | 19 | | 19 | | | $\text{nV}/\sqrt{\text{Hz}}$ |

PARAMETER MEASUREMENT INFORMATION



NOTE A: C_L includes fixture capacitance.

Figure 1. Slew Rate, Rise/Fall Time, and Overshoot Test Circuit

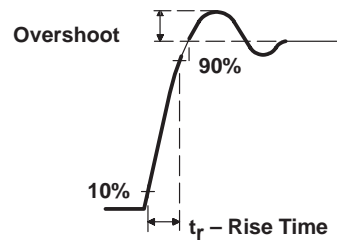


Figure 2. Rise Time and Overshoot Waveform

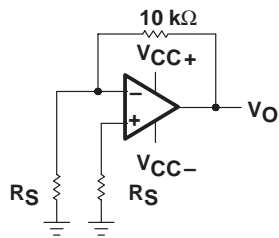
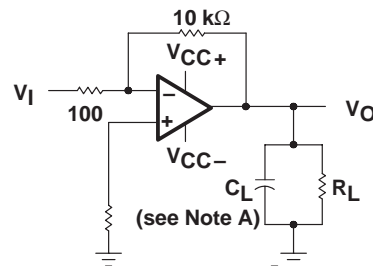


Figure 3. Noise Voltage Test Circuit



NOTE A: C_L includes fixture capacitance.

Figure 4. Unity-Gain Bandwidth and Phase Margin Test Circuit

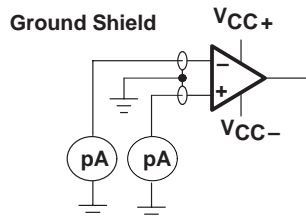


Figure 5. Input Bias and Offset Current Test Circuit

TL087, TL088, TL287, TL288

JFET-INPUT OPERATIONAL AMPLIFIERS

SLOS082A – D2484, MARCH 1979 – REVISED JANUARY 1993

typical values

Typical values as presented in this data sheet represent the median (50% point) of device parametric performance.

input bias and offset current

At the picoamp bias current level typical of these JFET operational amplifiers, accurate measurement of the bias current becomes difficult. Not only does this measurement require a picoammeter, but test socket leakages can easily exceed the actual device bias currents. To accurately measure these small currents, Texas Instruments uses a two-step process. The socket leakage is measured using picoammeters with bias voltages applied, but with no device in the socket. The device is then inserted in the socket and a second test that measures both the socket leakage and the device input bias current is performed. The two measurements are then subtracted algebraically to determine the bias current of the device.

TL087, TL088, TL287, TL288 JFET-INPUT OPERATIONAL AMPLIFIERS

SLOS082A – D2484, MARCH 1979 – REVISED JANUARY 1993

TYPICAL CHARACTERISTICS

table of graphs

| | | FIGURE | |
|-------------------|---|-------------------|------------|
| $\alpha_{V_{IO}}$ | Temperature coefficient of input offset voltage | Distribution | 6, 7 |
| I_{IO} | Input offset current | vs Temperature | 8 |
| I_{IB} | Input bias current | vs V_{IC} | 9 |
| | | vs Temperature | 8 |
| V_I | Common-mode input voltage range limits | vs V_{CC} | 10 |
| | | vs Temperature | 11 |
| V_{ID} | Differential input voltage | vs Output voltage | 12 |
| V_{OM} | Maximum peak output voltage swing | vs V_{CC} | 13 |
| | | vs Output current | 17 |
| | | vs Frequency | 14, 15, 16 |
| | | vs Temperature | 18 |
| A_{VD} | Differential voltage amplification | vs R_L | 19 |
| | | vs Frequency | 20 |
| | | vs Temperature | 21 |
| z_o | Output impedance | vs Frequency | 24 |
| CMRR | Common-mode rejection ratio | vs Frequency | 22 |
| | | vs Temperature | 23 |
| k_{SVR} | Supply-voltage rejection ratio | vs Temperature | 25 |
| I_{OS} | Short-circuit output current | vs V_{CC} | 26 |
| | | vs Time | 27 |
| | | vs Temperature | 28 |
| I_{CC} | Supply current | vs V_{CC} | 29 |
| | | vs Temperature | 30 |
| SR | Slew rate | vs R_L | 31 |
| | | vs Temperature | 32 |
| | Overshoot factor | vs C_L | 33 |
| V_n | Equivalent input noise voltage | vs Frequency | 34 |
| THD | Total harmonic distortion | vs Frequency | 35 |
| B_1 | Unity-gain bandwidth | vs V_{CC} | 36 |
| | | vs Temperature | 37 |
| ϕ_m | Phase margin | vs V_{CC} | 38 |
| | | vs C_L | 39 |
| | | vs Temperature | 40 |
| | Phase shift | vs Frequency | 20 |
| | Pulse response | Small-signal | 41 |
| | | Large-signal | 42 |

TL087, TL088, TL287, TL288 JFET-INPUT OPERATIONAL AMPLIFIERS

SLOS082A – D2484, MARCH 1979 – REVISED JANUARY 1993

TYPICAL CHARACTERISTICS†

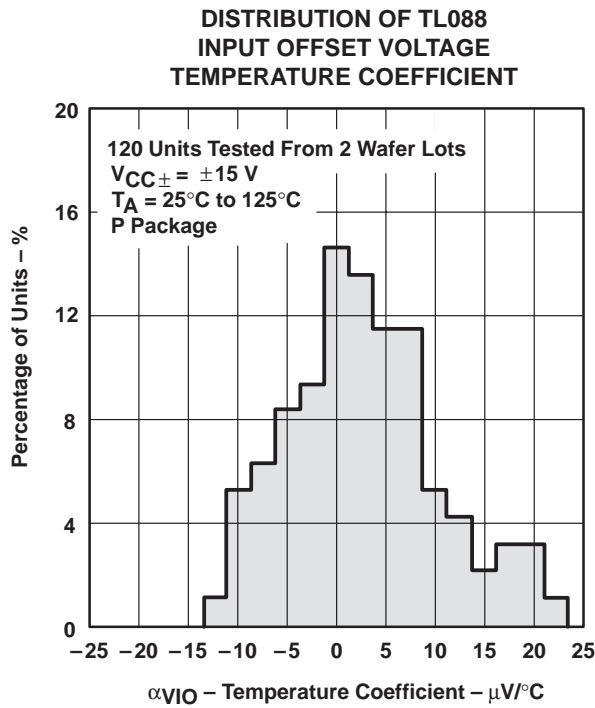


Figure 6

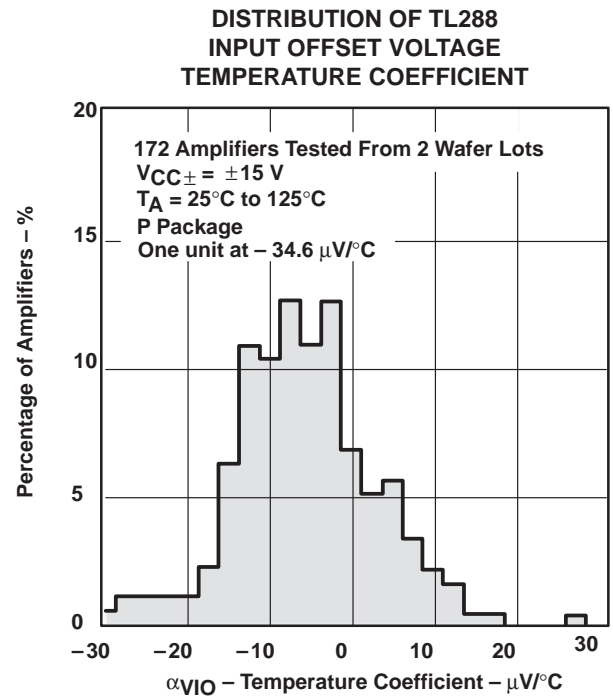


Figure 7

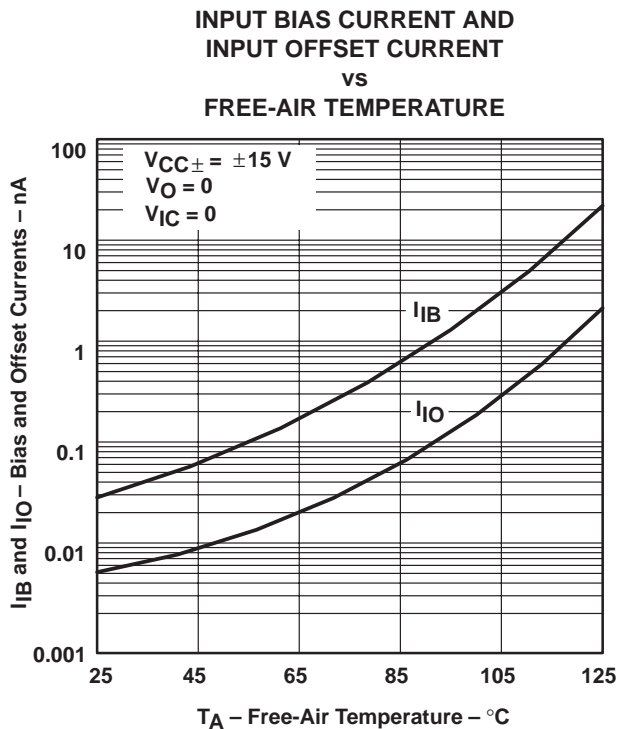


Figure 8

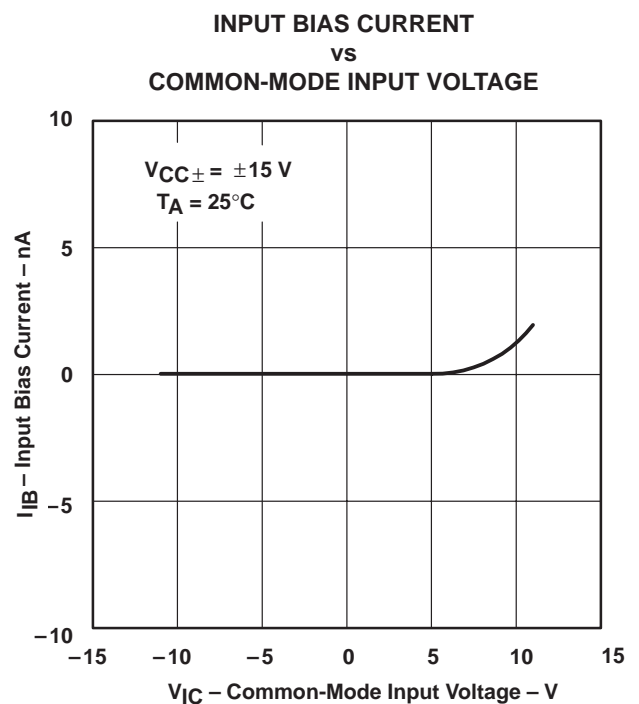


Figure 9

† Data at high and low temperatures are applicable within the rated operating free-air temperature ranges of the various devices.

TL087, TL088, TL287, TL288 JFET-INPUT OPERATIONAL AMPLIFIERS

SLOS082A – D2484, MARCH 1979 – REVISED JANUARY 1993

TYPICAL CHARACTERISTICS†

COMMON-MODE
INPUT VOLTAGE RANGE LIMITS
vs
SUPPLY VOLTAGE

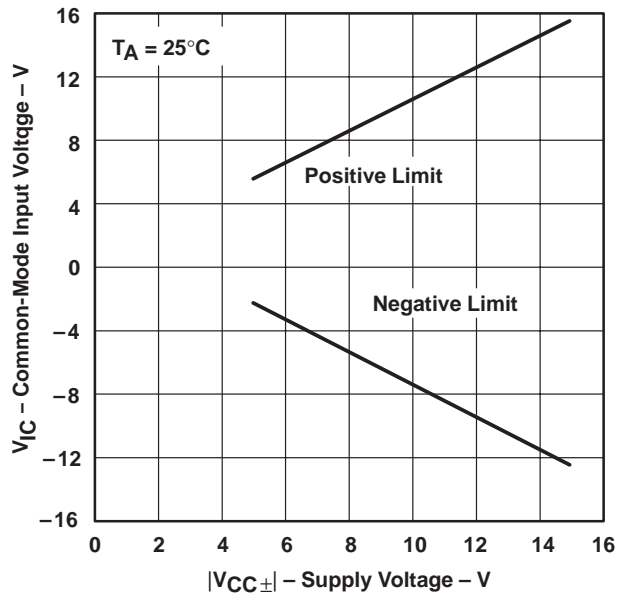


Figure 10

COMMON-MODE
INPUT VOLTAGE RANGE LIMITS
vs
FREE-AIR TEMPERATURE

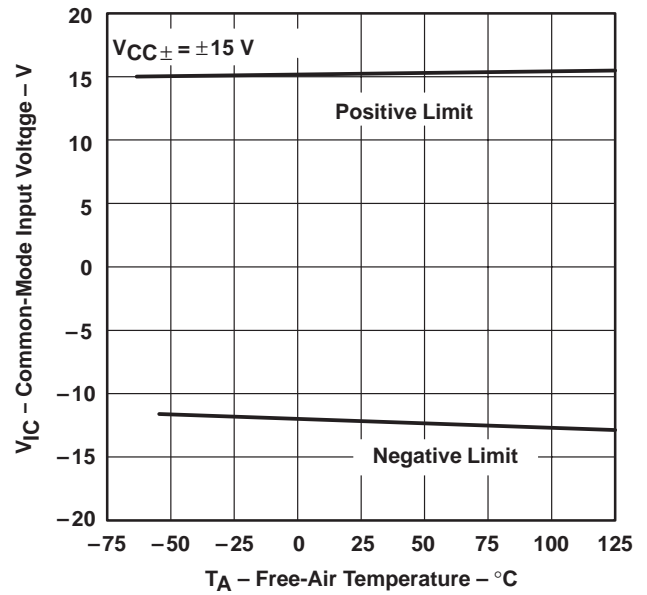


Figure 11

OUTPUT VOLTAGE
vs
DIFFERENTIAL INPUT VOLTAGE

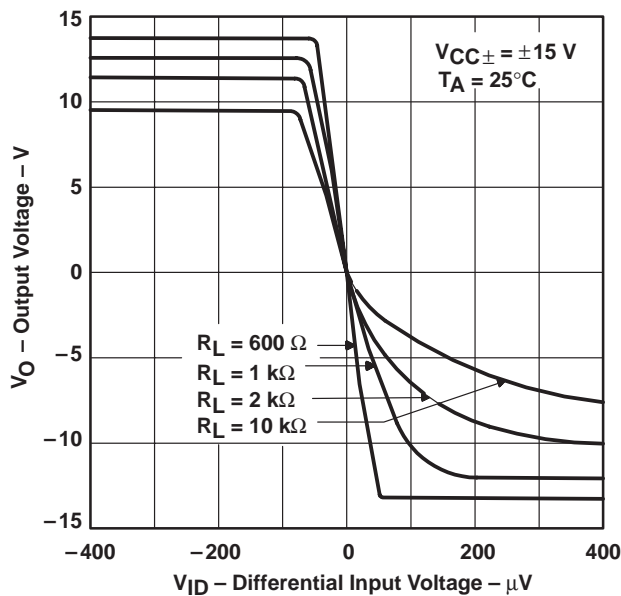


Figure 12

MAXIMUM PEAK OUTPUT VOLTAGE
vs
SUPPLY VOLTAGE

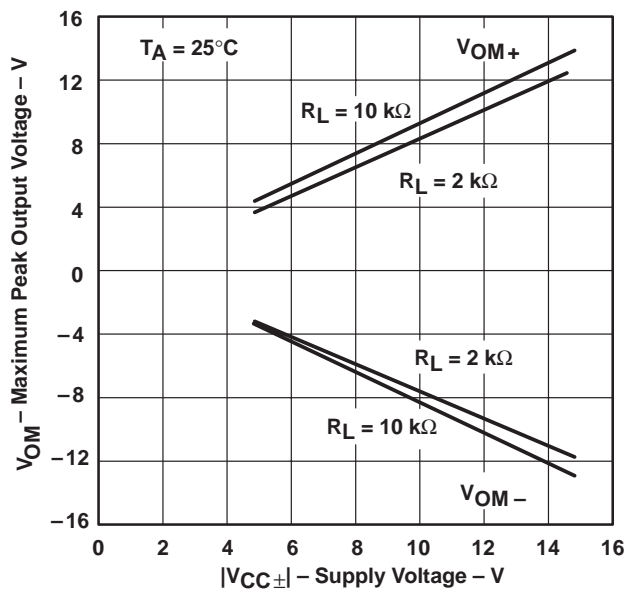


Figure 13

† Data at high and low temperatures are applicable within the rated operating free-air temperature ranges of the various devices.

TL087, TL088, TL287, TL288 JFET-INPUT OPERATIONAL AMPLIFIERS

SLOS082A – D2484, MARCH 1979 – REVISED JANUARY 1993

TYPICAL CHARACTERISTICS†

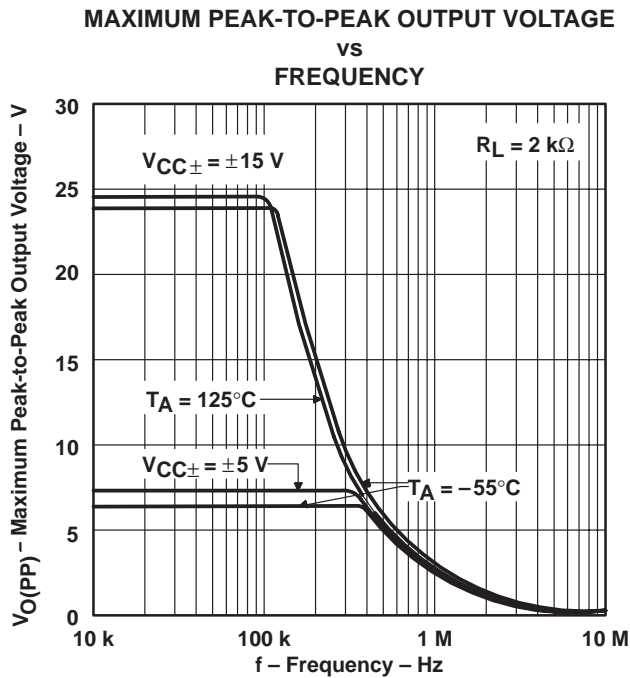


Figure 14

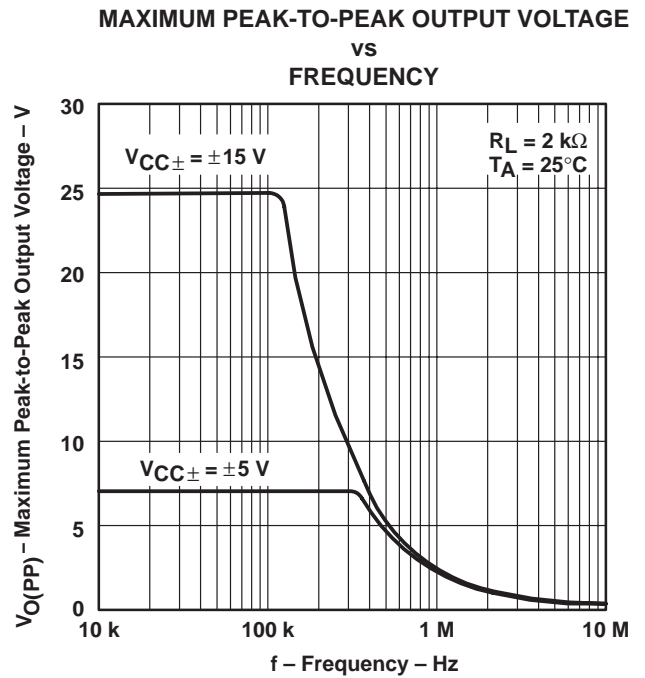


Figure 15

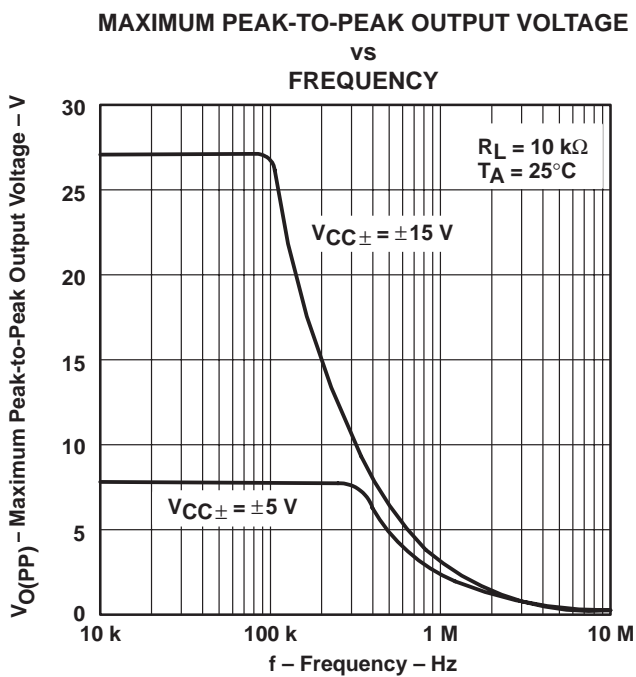


Figure 16

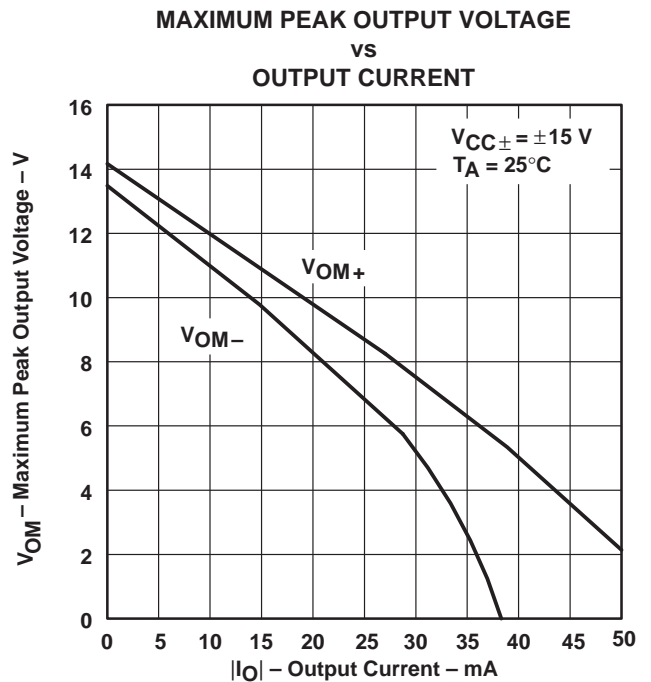


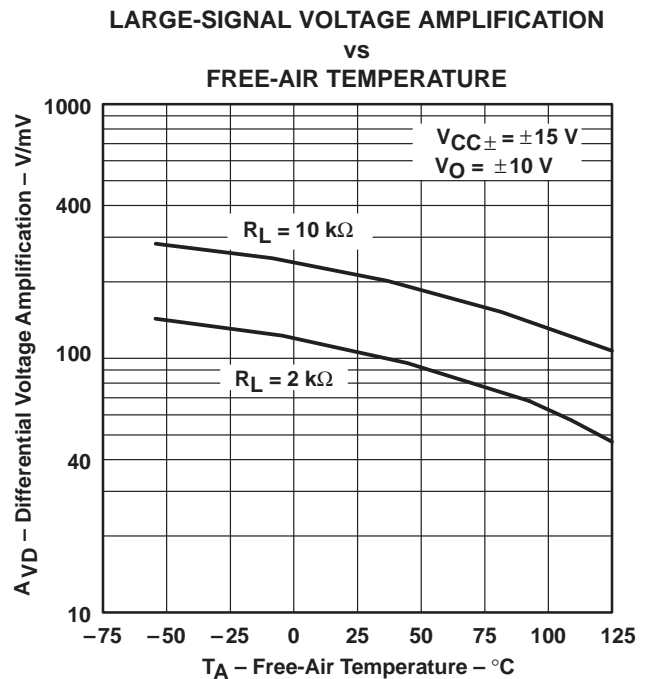
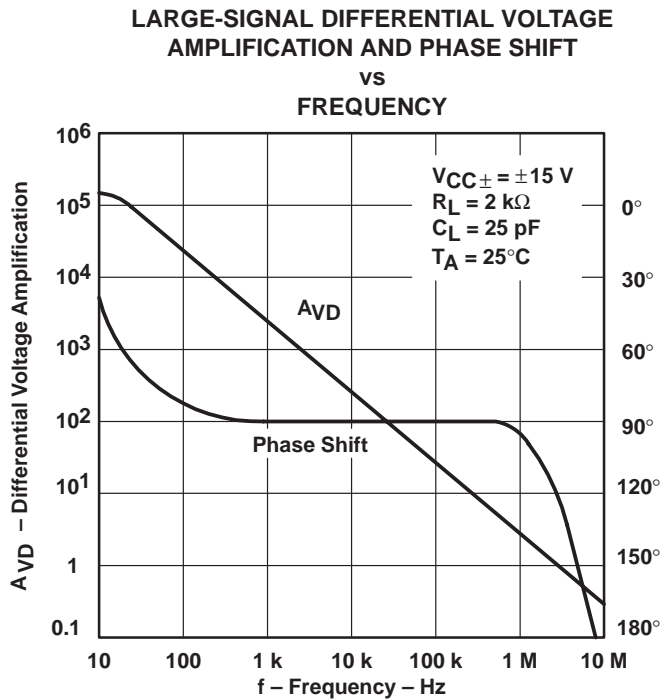
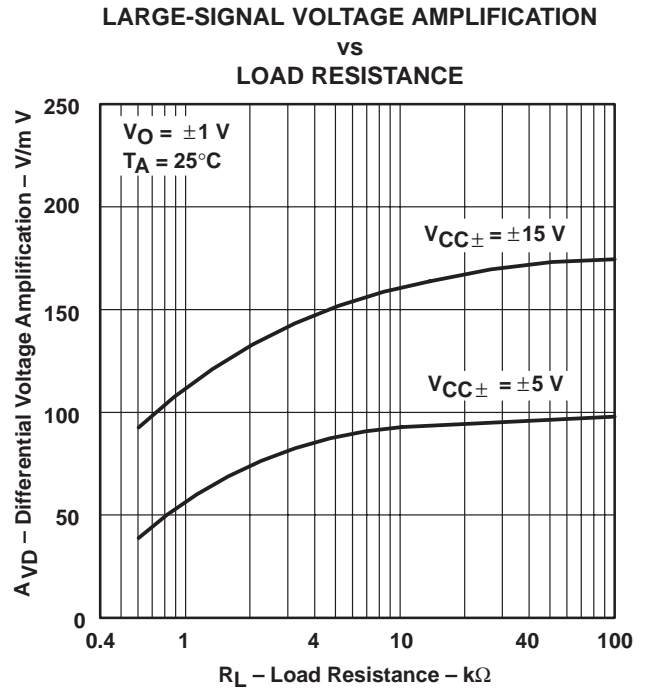
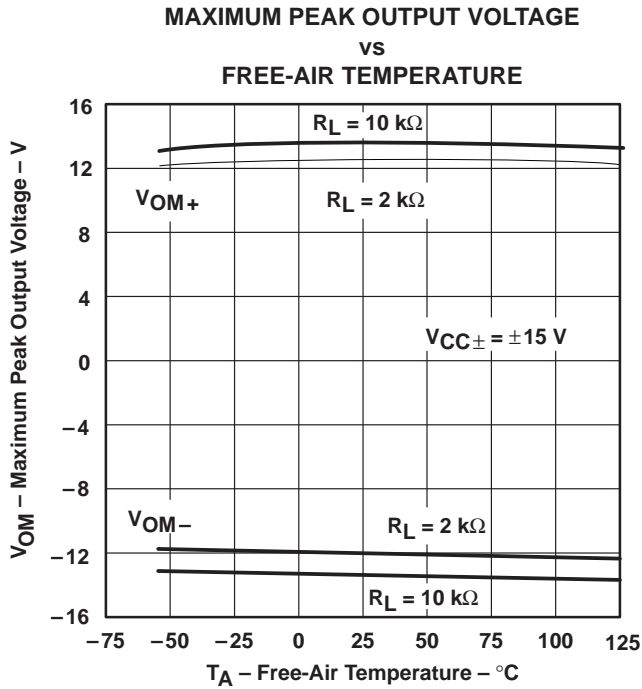
Figure 17

† Data at high and low temperatures are applicable within the rated operating free-air temperature ranges of the various devices.

TL087, TL088, TL287, TL288 JFET-INPUT OPERATIONAL AMPLIFIERS

SLOS082A – D2484, MARCH 1979 – REVISED JANUARY 1993

TYPICAL CHARACTERISTICS†



† Data at high and low temperatures are applicable within the rated operating free-air temperature ranges of the various devices.

TL087, TL088, TL287, TL288 JFET-INPUT OPERATIONAL AMPLIFIERS

SLOS082A – D2484, MARCH 1979 – REVISED JANUARY 1993

TYPICAL CHARACTERISTICS†

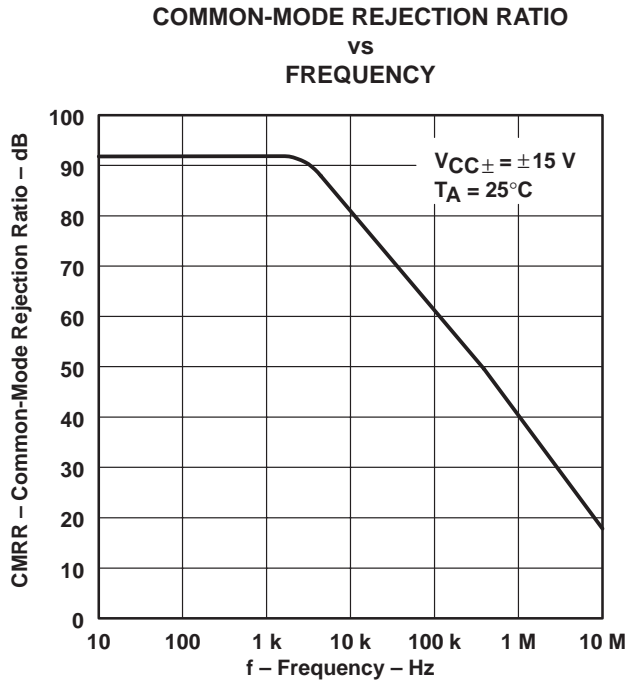


Figure 22

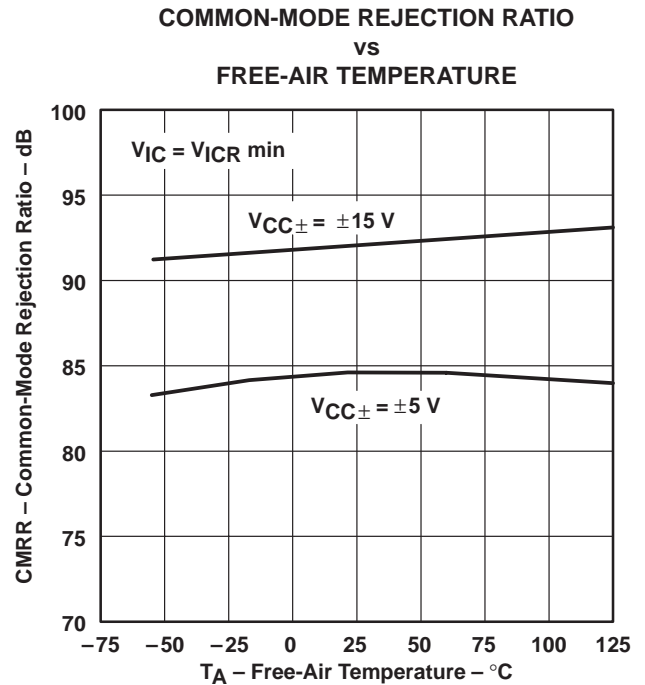


Figure 23

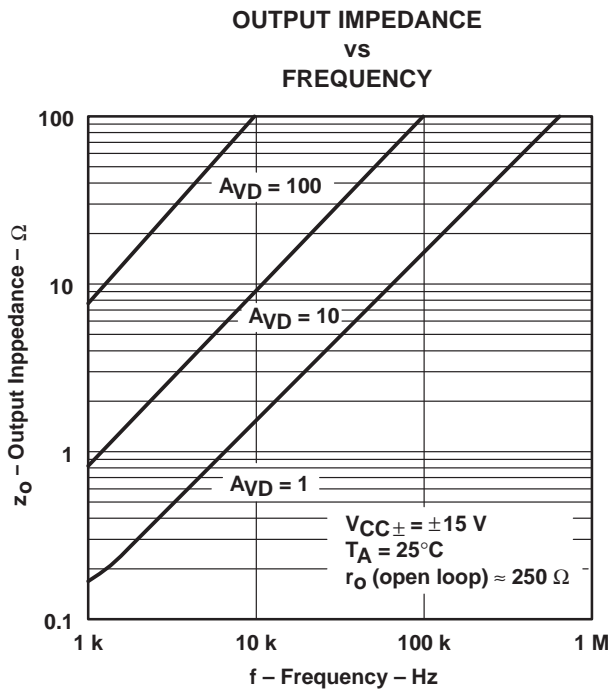


Figure 24

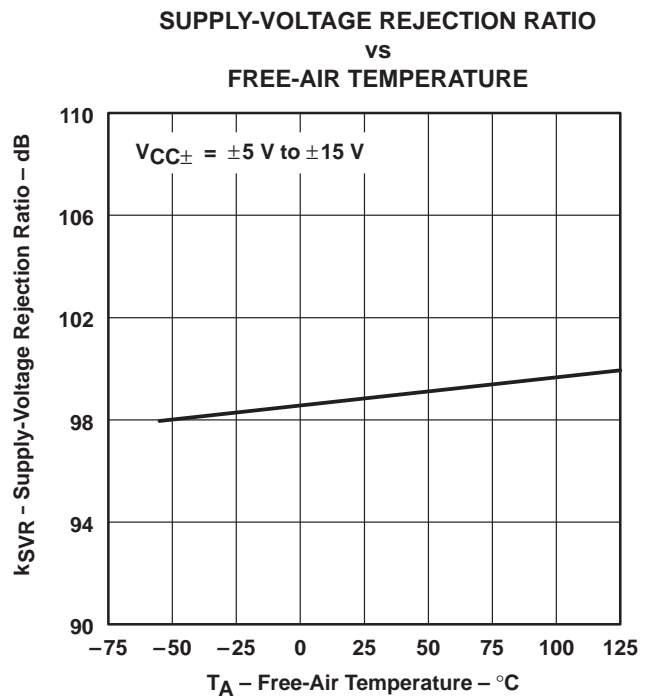


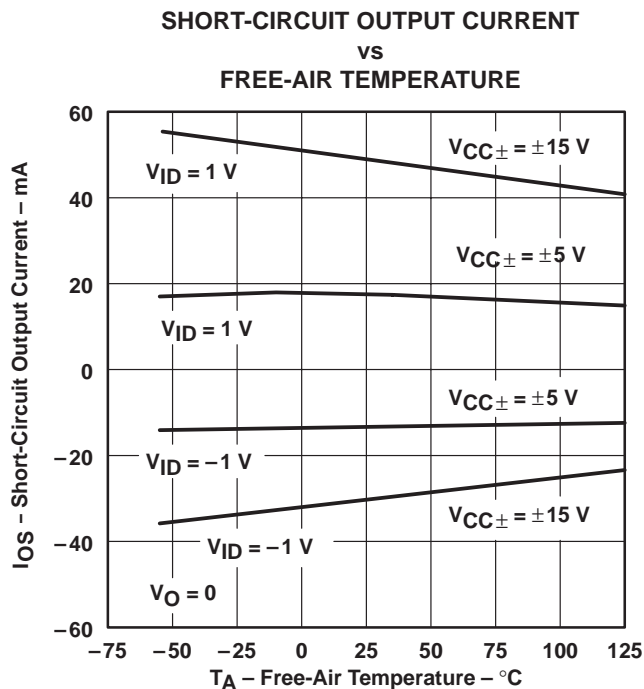
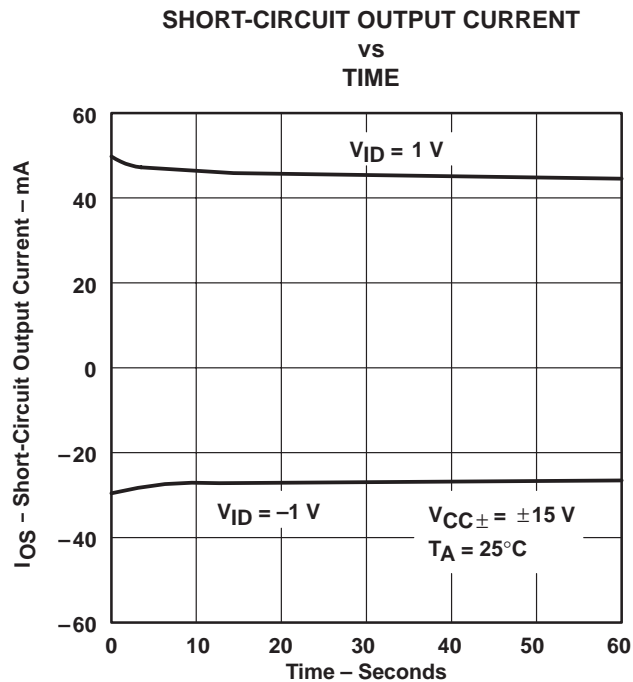
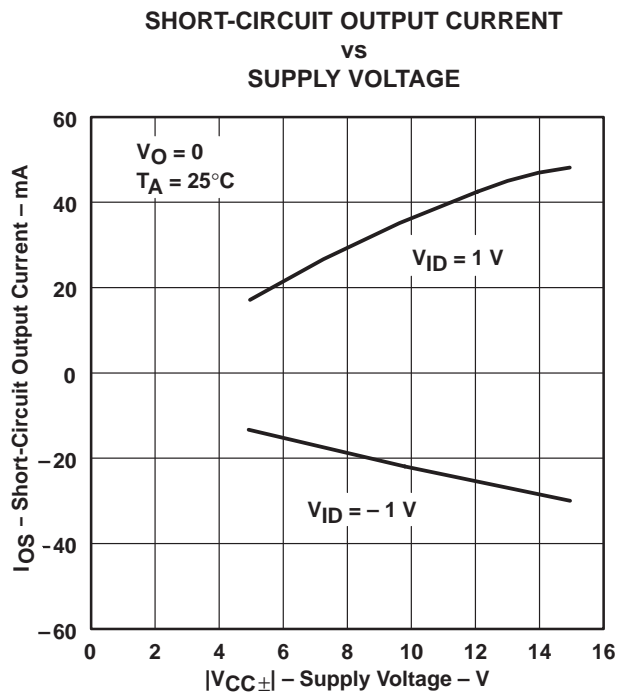
Figure 25

† Data at high and low temperatures are applicable within the rated operating free-air temperature ranges of the various devices.

TL087, TL088, TL287, TL288 JFET-INPUT OPERATIONAL AMPLIFIERS

SLOS082A – D2484, MARCH 1979 – REVISED JANUARY 1993

TYPICAL CHARACTERISTICS†



† Data at high and low temperatures are applicable within the rated operating free-air temperature ranges of the various devices.

TL087, TL088, TL287, TL288 JFET-INPUT OPERATIONAL AMPLIFIERS

SLOS082A – D2484, MARCH 1979 – REVISED JANUARY 1993

TYPICAL CHARACTERISTICS†

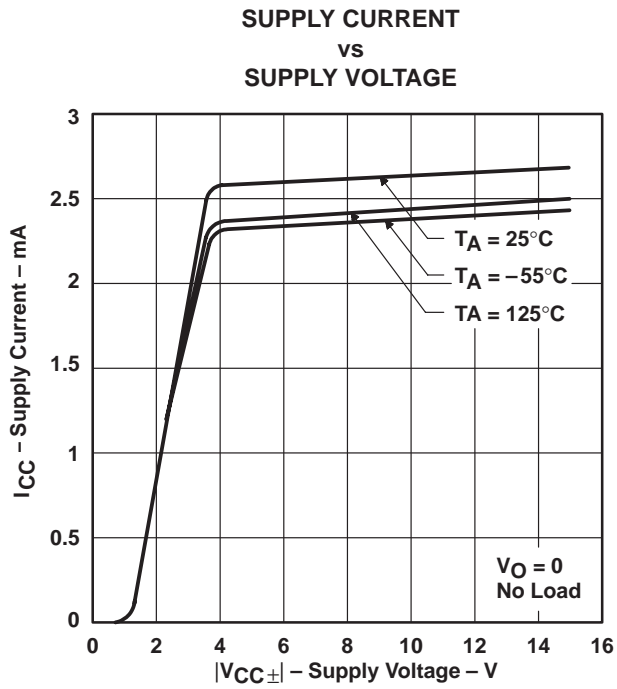


Figure 29

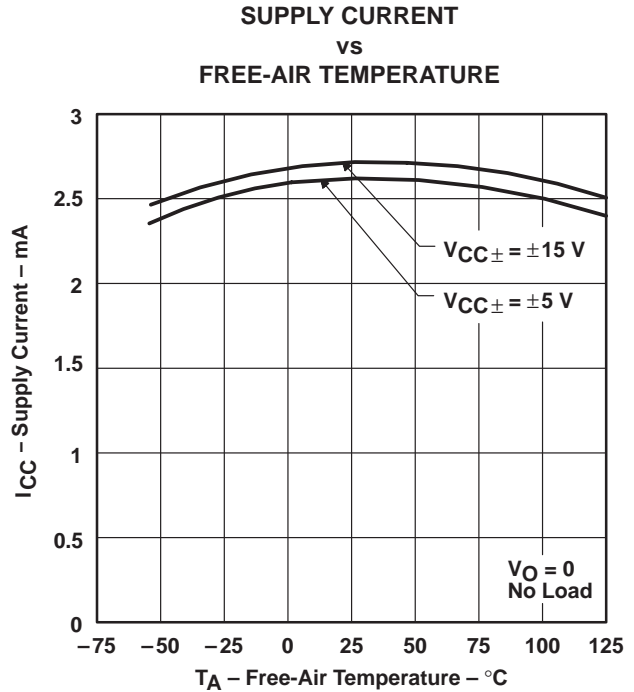


Figure 30

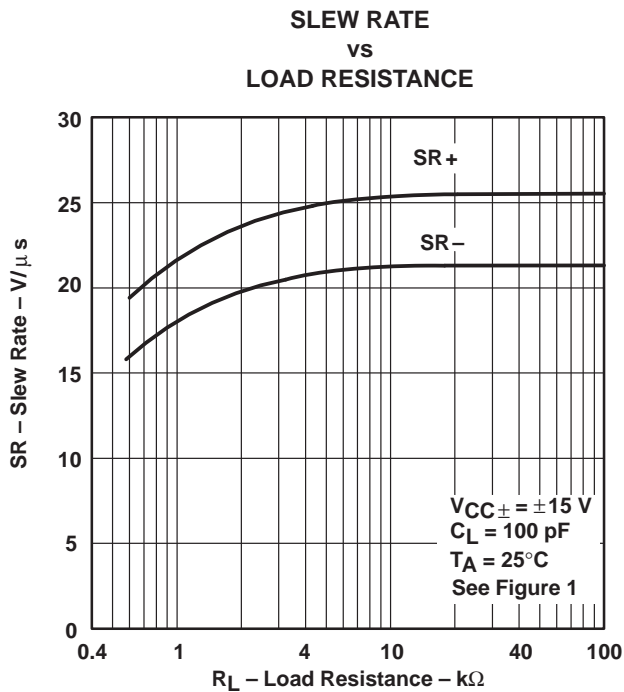


Figure 31

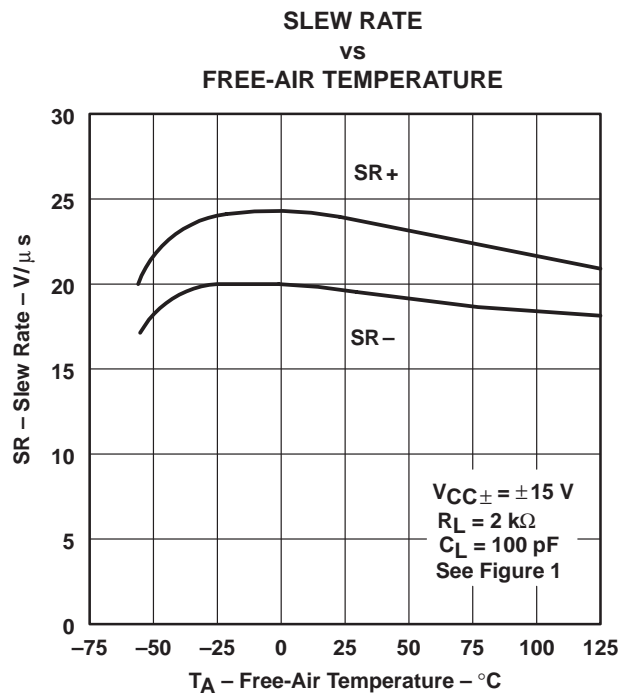


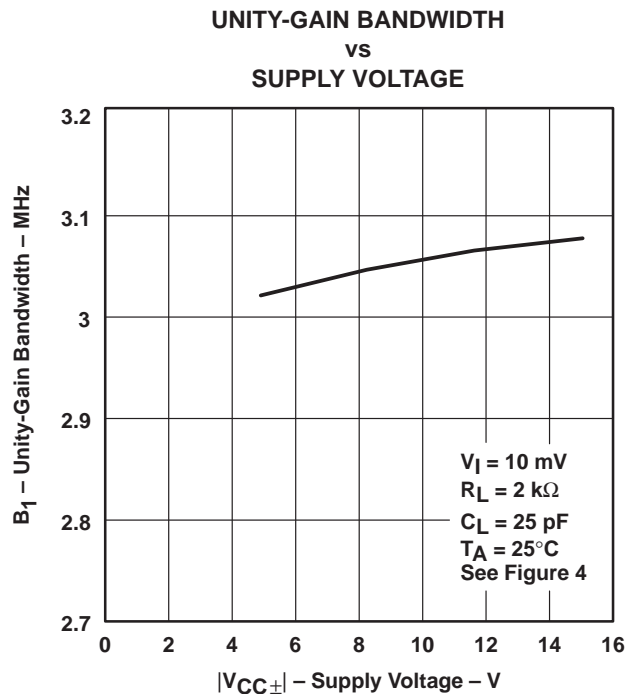
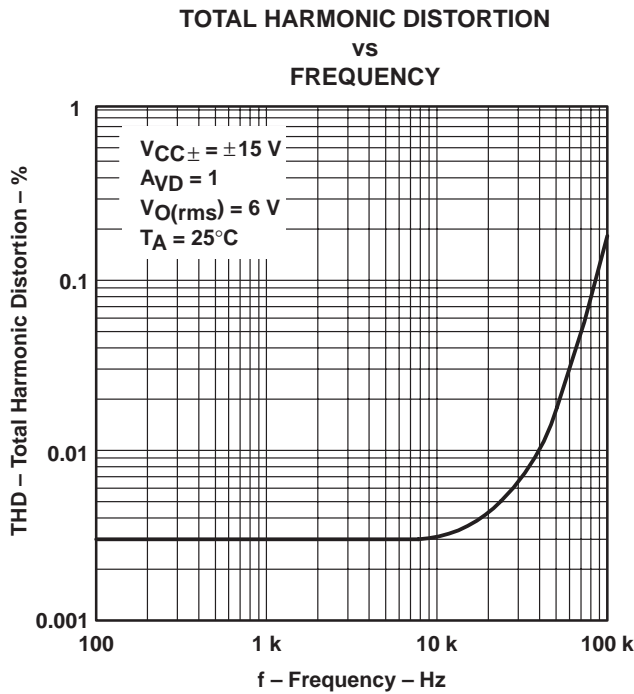
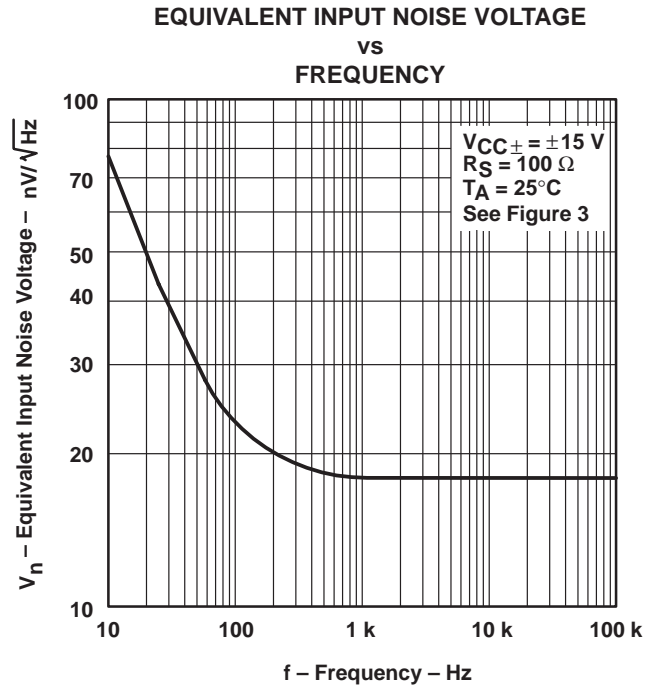
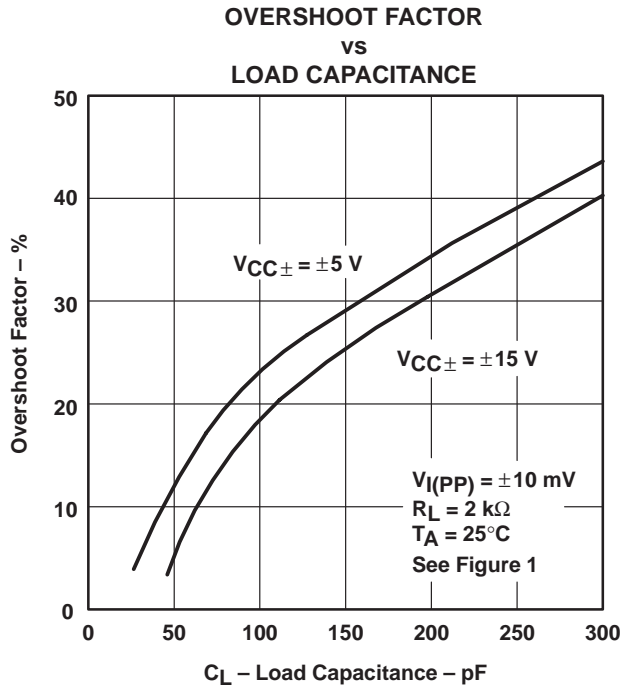
Figure 32

† Data at high and low temperatures are applicable within the rated operating free-air temperature ranges of the various devices.

TL087, TL088, TL287, TL288 JFET-INPUT OPERATIONAL AMPLIFIERS

SLOS082A – D2484, MARCH 1979 – REVISED JANUARY 1993

TYPICAL CHARACTERISTICS†



† Data at high and low temperatures are applicable within the rated operating free-air temperature ranges of the various devices.

TL087, TL088, TL287, TL288 JFET-INPUT OPERATIONAL AMPLIFIERS

SLOS082A – D2484, MARCH 1979 – REVISED JANUARY 1993

TYPICAL CHARACTERISTICS†

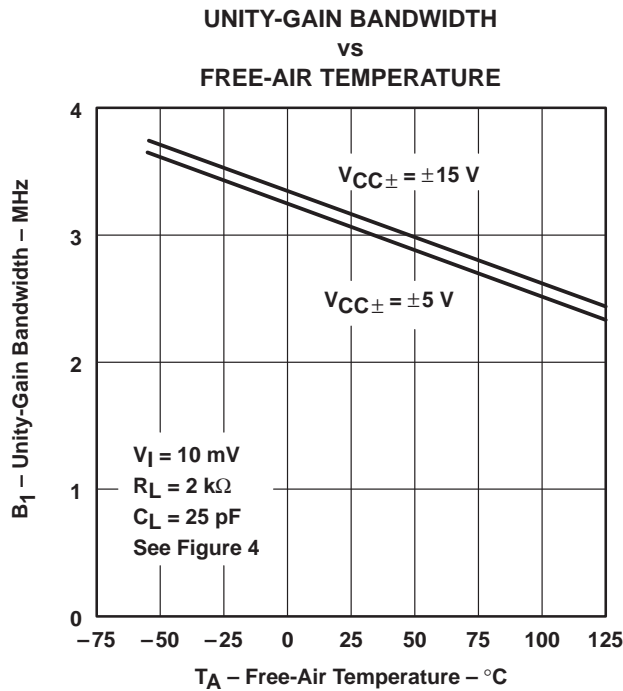


Figure 37

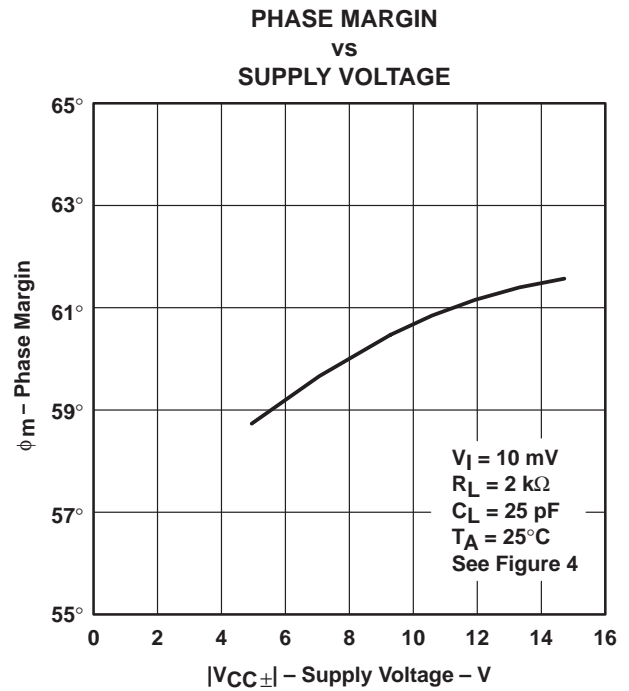


Figure 38

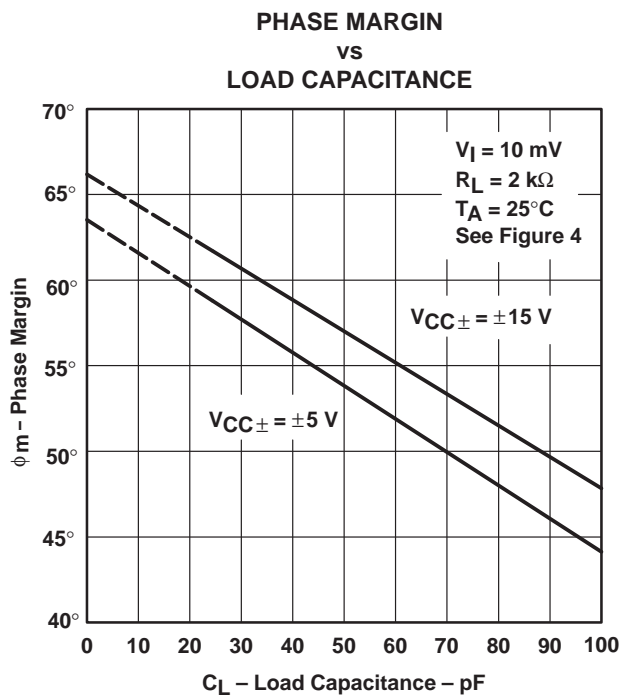


Figure 39

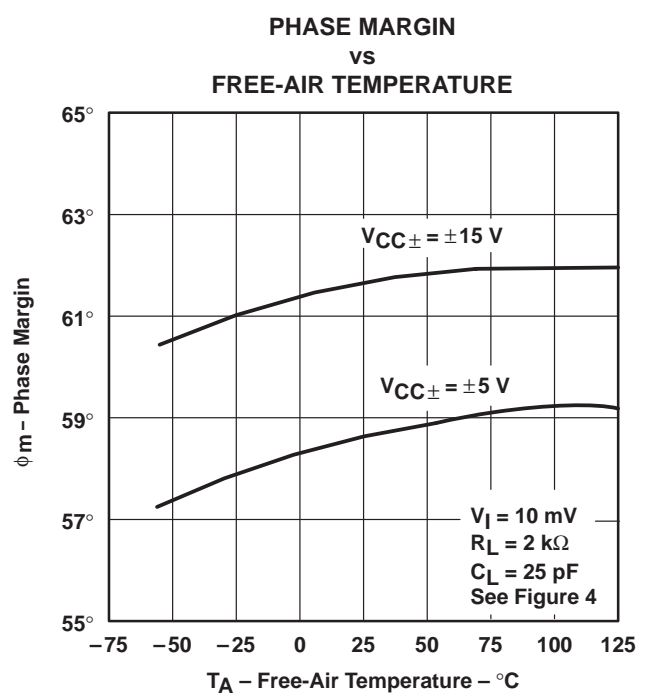


Figure 40

† Data at high and low temperatures are applicable within the rated operating free-air temperature ranges of the various devices.

TL087, TL088, TL287, TL288 JFET-INPUT OPERATIONAL AMPLIFIERS

SLOS082A – D2484, MARCH 1979 – REVISED JANUARY 1993

TYPICAL CHARACTERISTICS

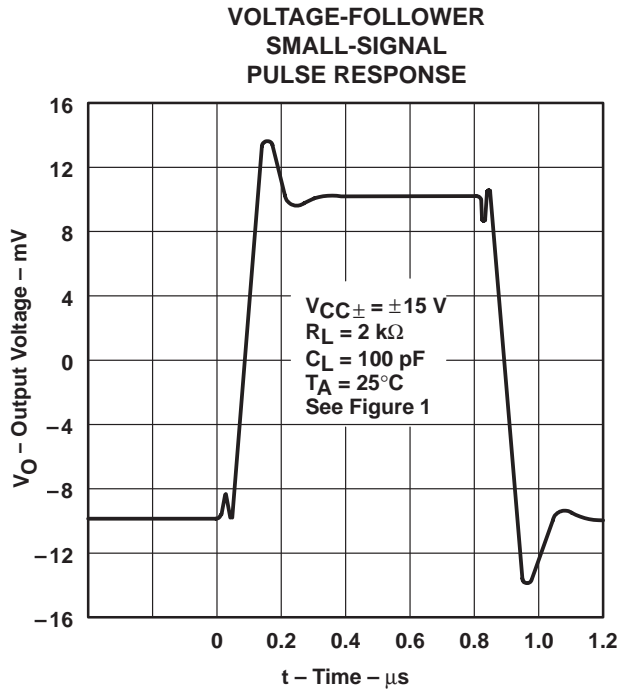


Figure 41

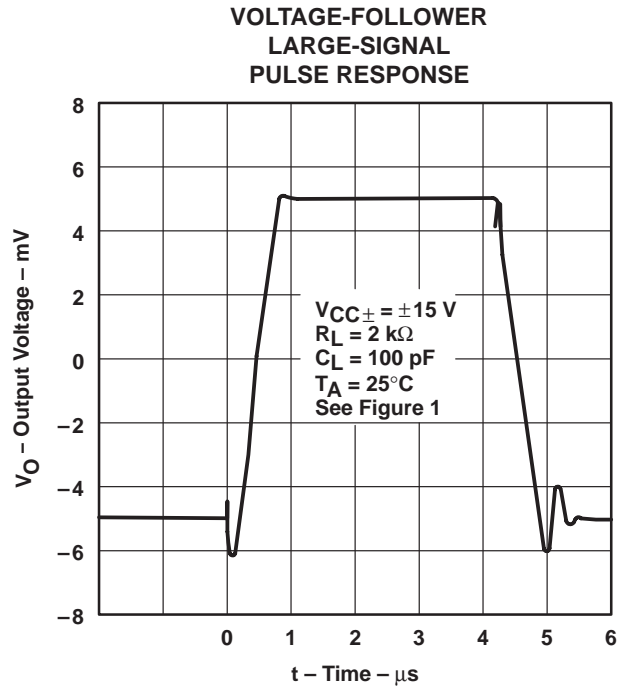


Figure 42

TL087, TL088, TL287, TL288 JFET-INPUT OPERATIONAL AMPLIFIERS

SLOS082A – D2484, MARCH 1979 – REVISED JANUARY 1993

TYPICAL APPLICATION DATA

output characteristics

All operating characteristics are specified with 100-pF load capacitance. These amplifiers will drive higher capacitive loads; however, as the load capacitance increases, the resulting response pole occurs at lower frequencies, thereby causing ringing, peaking, or even oscillation. The value of the load capacitance at which oscillation occurs varies with production lots. If an application appears to be sensitive to oscillation due to load capacitance, adding a small resistance in series with the load should alleviate the problem. Capacitive loads of 1000 pF and larger may be driven if enough resistance is added in series with the output (see Figure 43).

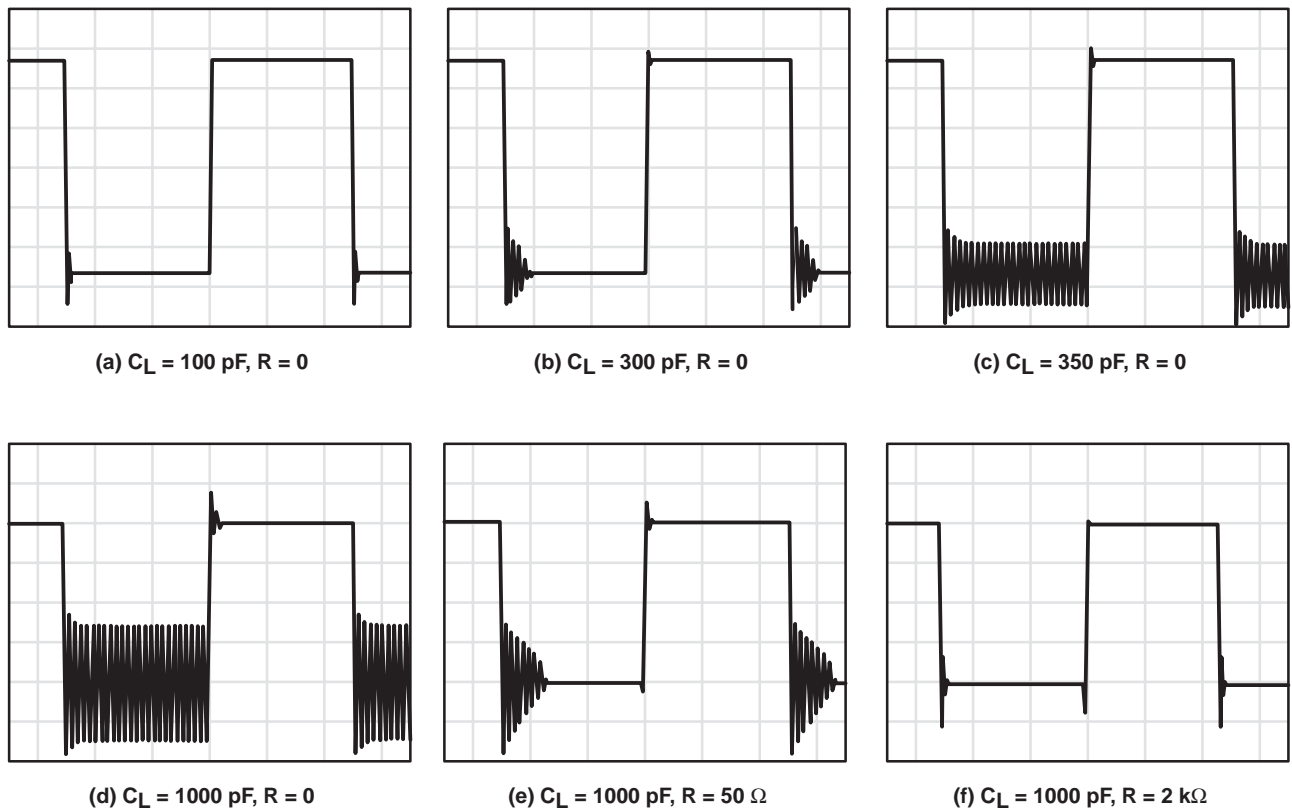
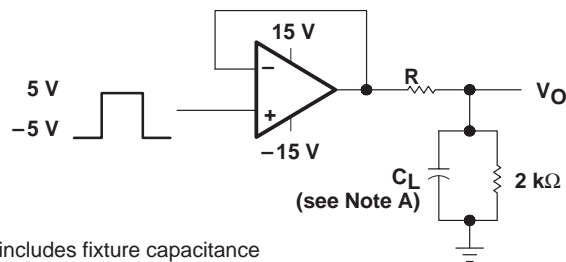


Figure 43. Effect of Capacitive Loads



NOTE A: C_L includes fixture capacitance

Figure 44. Test Circuit for Output Characteristics

TYPICAL APPLICATION DATA

input characteristics

These amplifiers are specified with a minimum and a maximum input voltage that, if exceeded at either input, could cause the device to malfunction.

Because of the extremely high input impedance and resulting low bias current requirements, these amplifiers are well suited for low-level signal processing; however, leakage currents on printed circuit boards and sockets can easily exceed bias current requirements and cause degradation in system performance. It is good practice to include guard rings around inputs (see Figure 45). These guards should be driven from a low-impedance source at the same voltage level as the common-mode input.

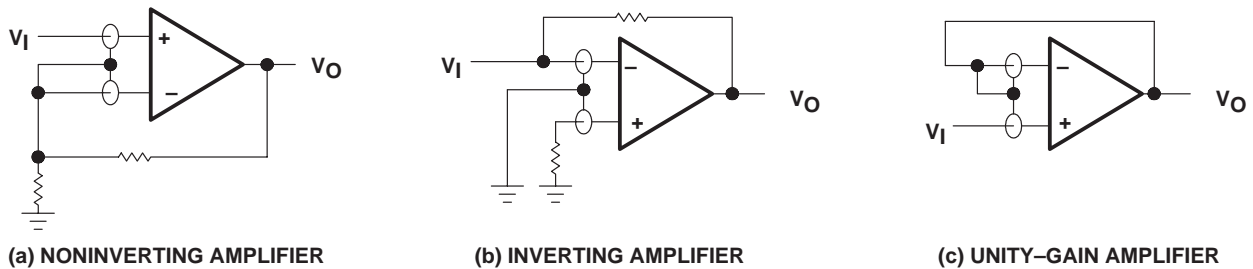


Figure 45. Use of Guard Rings

noise performance

The noise specifications in op amp circuits are greatly dependent on the current in the first-stage differential amplifier. The low input bias current requirements of these amplifiers result in a very low current noise. This feature makes the devices especially favorable over bipolar devices when using values of circuit impedance greater than 50 kΩ.

IMPORTANT NOTICE

Texas Instruments (TI) reserves the right to make changes to its products or to discontinue any semiconductor product or service without notice, and advises its customers to obtain the latest version of relevant information to verify, before placing orders, that the information being relied on is current and complete.

TI warrants performance of its semiconductor products and related software to the specifications applicable at the time of sale in accordance with TI's standard warranty. Testing and other quality control techniques are utilized to the extent TI deems necessary to support this warranty. Specific testing of all parameters of each device is not necessarily performed, except those mandated by government requirements.

Certain applications using semiconductor products may involve potential risks of death, personal injury, or severe property or environmental damage ("Critical Applications").

TI SEMICONDUCTOR PRODUCTS ARE NOT DESIGNED, INTENDED, AUTHORIZED, OR WARRANTED TO BE SUITABLE FOR USE IN LIFE-SUPPORT APPLICATIONS, DEVICES OR SYSTEMS OR OTHER CRITICAL APPLICATIONS.

Inclusion of TI products in such applications is understood to be fully at the risk of the customer. Use of TI products in such applications requires the written approval of an appropriate TI officer. Questions concerning potential risk applications should be directed to TI through a local SC sales office.

In order to minimize risks associated with the customer's applications, adequate design and operating safeguards should be provided by the customer to minimize inherent or procedural hazards.

TI assumes no liability for applications assistance, customer product design, software performance, or infringement of patents or services described herein. Nor does TI warrant or represent that any license, either express or implied, is granted under any patent right, copyright, mask work right, or other intellectual property right of TI covering or relating to any combination, machine, or process in which such semiconductor products or services might be or are used.